

Driver Characteristics

Parameter	Rating	Units
Input Current	2.5	mA
Switching Speed ($I_F=5\text{mA}$, MOS Input Capacitance=4nF)		
$t_{d(on)}$	12	μs
$t_{d(off1)}$ ($V_{GS}=2\text{V}$)	125	
$t_{d(off2)}$ ($V_{GS}=1\text{V}$)	210	

Features

- 3750V_{rms} Input-to-Output Isolation
- Drives External Power MOSFET
- Low LED Current (2.5mA)
- Requires No External Power Supply
- Load Voltages up to 200V
- High Reliability
- Small 8-pin Surface Mount Flatpack Package
- Machine Insertable, Wave Solderable
- Tape and Reel Version Available
- Flammability Rating UL 94 V-0

Applications

- Industrial Controls
- Instrumentation
- Medical Equipment Isolation
- Electronic Switching
- I/O Subsystems



• Appliances

Description

The CPC1590 is a MOSFET Gate Driver that requires no external power supply: it regulates the input voltage drawn from the load (up to 200V), down to 12.2V for internal use. It is specifically designed for low duty cycle switching applications that drive up to 4nF of gate capacitance.

The CPC1590 accomplishes very fast MOSFET turn-on by supplying stored charge, from an external capacitor, to the MOSFET gate when input control current is applied to the device's LED. After the MOSFET is turned on, photocurrent from the input optocoupler keeps it on for as long as sufficient input control current flows, so there is no low-frequency operating limit. When the MOSFET is turned off, the storage capacitor charges from the device's regulated internal voltage in preparation for the next turn-on.

Because it is provided in a small, 8-pin Flatpack package and requires no separate power supply, the CPC1590 provides a flexible design solution that consumes the least amount of PCB land area.

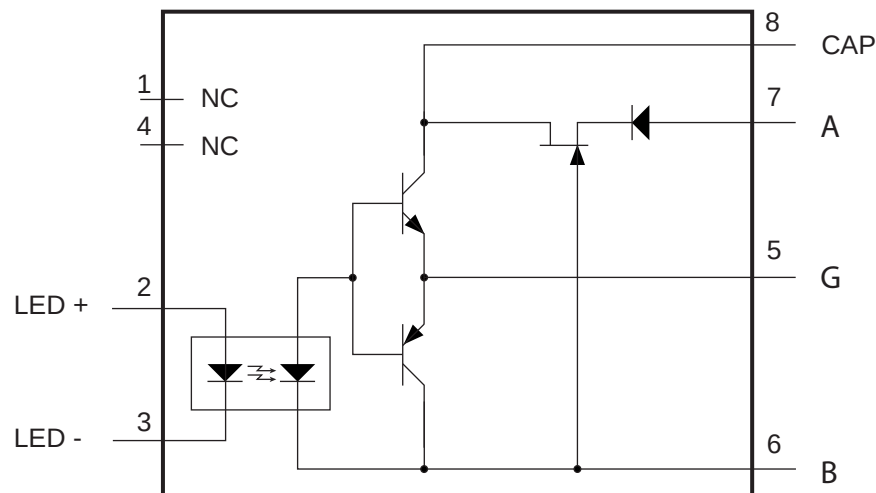
Approvals

- UL Recognized Component: File E76270

Ordering Information

Part	Description
CPC1590P	8-Pin Flatpack (50/Tube)
CPC1590PTR	8-Pin Flatpack (1000/Reel)

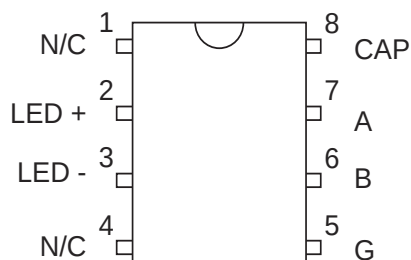
Figure 1. CPC1590 Block Diagram



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1. Specifications

1.1 Package Pinout



1.2 Pin Description

Pin#	Name	Description
1	-	Not connected
2	LED +	Positive input to LED
3	LED -	Negative input to LED
4	-	Not connected
5	V_G	Output, MOSFET Gate Control
6	V_{L2}	-Load Voltage DC, $\pm$ Load Voltage AC
7	V_{L1}	+Load Voltage DC, $\pm$ Load Voltage AC
8	V_{CAP}	Storage Capacitor Voltage

1.3 Absolute Maximum Ratings

Parameter	Rating	Units
Blocking Voltage (V_{DS})	200	V_P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation	20	mW
Total Package Dissipation	200	mW
Isolation Voltage (Input to Output)	3750	V_{rms}
Operational Temperature	-40 to +110	$^{\circ}C$
Storage Temperature	-40 to +125	$^{\circ}C$

Absolute maximum electrical ratings are at 25 $^{\circ}C$

Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

1.4 ESD Rating

ESD Rating (Human Body Model)
1000 V

1.5 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Units
Load Voltage	V_L	15	200	V
Input Control Current	I_F	2.5	10	mA
Forward Voltage Drop	V_F	1	1.5	V
Operating Temperature	T_A	-40	+110	$^{\circ}C$

1.6 General Conditions

Unless otherwise specified, minimum and maximum values are guaranteed by production testing.

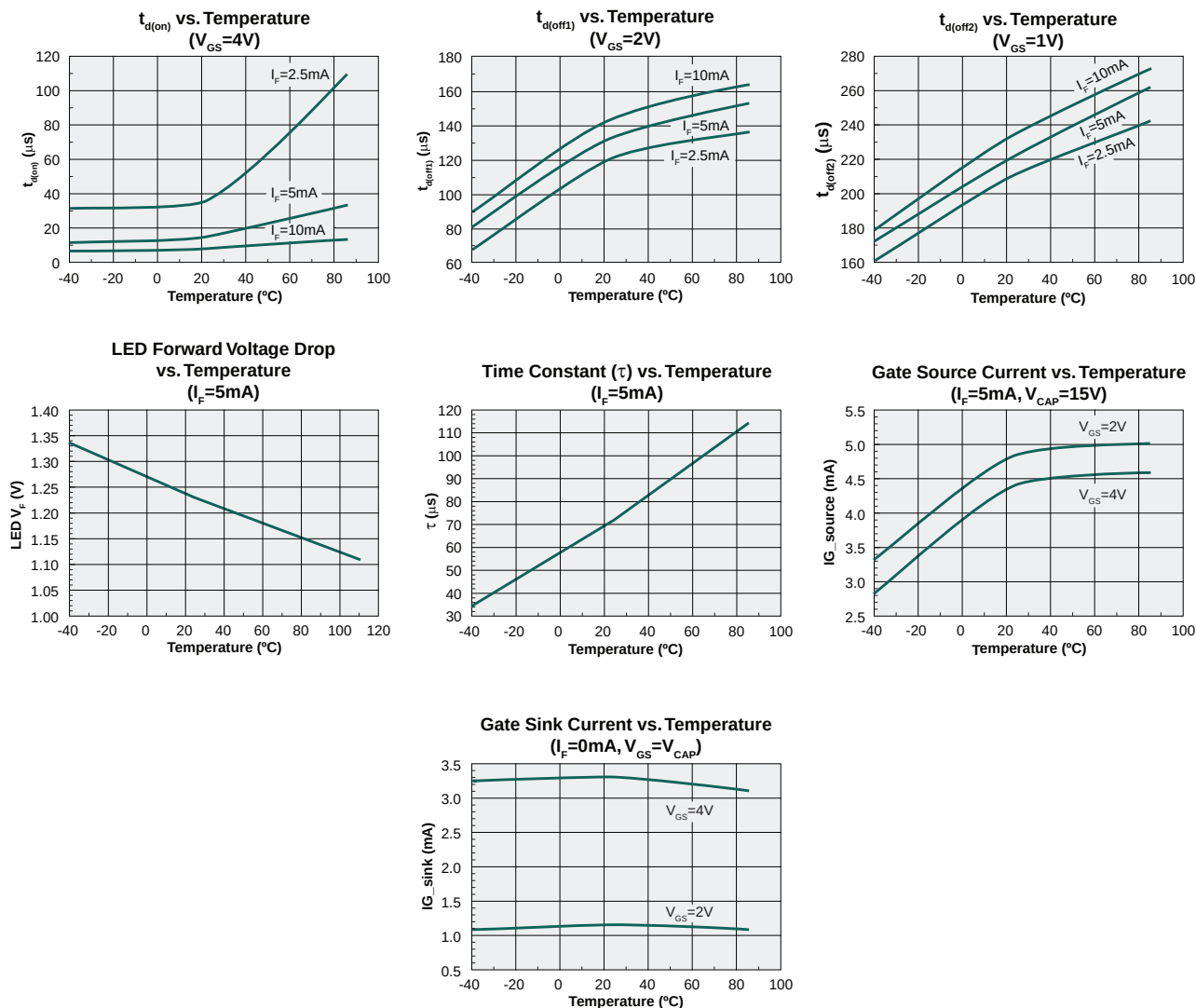
Typical values are characteristic of the device at 25°C and are the result of engineering evaluations. They are provided for informational purposes only and are not part of the manufacturing testing requirements.

Unless otherwise noted, all electrical specifications are listed for $T_A=25^\circ\text{C}$.

1.7 Electrical Specifications

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Load Side Characteristics						
Gate Voltage	I _F =2.5mA	V _{GS}	7.0	7.3	12	V
	I _F =5mA		7.5	8.0		
	I _F =10mA			8.4		
	I _F =2.5mA -40°C<T _A <110°C		4.2	-	14.4	
Capacitor Voltage	10V<V _{DS} <200V	V _{CAP}	10	12.2	16	V
Gate Drive Capability	I _F =2.5mA, V _{GS} =0V, V _{CAP} =15V	I _{G_source}	2	3.3	7	mA
	I _F =0mA, V _{GS} =8V, V _{CAP} =8V	I _{G_sink}	4.0	9.0	14	
	I _F =0mA, V _{GS} =4V, V _{CAP} =4V		1.5	3.3	6	
	I _F =0mA, V _{GS} =2V, V _{CAP} =2V		0.5	1.2	2	
Turn-On Delay	V _{DS} =48V, V _{GS} =4V, C _{VG} =4nF	t _{on}				μs
	I _F =2.5mA		1	40	140	
	I _F =5mA			12	40	
	I _F =10mA			5	20	
Turn-Off Delay	V _{DS} =48V, V _{GS} =2V, C _{VG} =4nF	t _{off1}				μs
	I _F =2.5mA		40	110	400	
	I _F =5mA			125		
	I _F =10mA			130		
	V _{DS} =48V, V _{GS} =1V, C _{VG} =4nF	t _{off2}				μs
	I _F =2.5mA		40	200	600	
	I _F =5mA			210		
	I _F =10mA			220		
Off-State Leakage Current	V _{DS} =200V	I _{DS}	-	-	1	μA
LED Characteristics						
Forward Voltage Drop	I _F =5mA	V _F	1	1.27	1.5	V
Input Dropout Current	V _{GS} =1V	I _F	0.2	0.75	1	mA
Reverse Bias Leakage Current	V _R =5V	I _R	-	-	10	μA
Common Characteristics						
Input to Output Capacitance	-	C _{IO}	-	3	-	pF

1.8 Performance Data*



* Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C. For guaranteed parameters not indicated in the written specifications, please contact our application department.

2. Introduction

The CPC1590 is a MOSFET Gate Driver that requires no external power supply. It can regulate an input voltage, up to 200V, down to 12.2V for internal use. It is specifically designed for low-duty-cycle switching frequencies that drive 4nF of gate capacitance.

3. Functional Description

The CPC1590 is used in conjunction with a single MOSFET transistor for remote switching of DC loads (**Figure 2**), and two MOSFETs and a diode for remote switching of low-frequency AC loads (**Figure 3**) where isolated power is unavailable.

The device uses external components, most notably a charge storage capacitor, to satisfy design switching and over-voltage protection requirements. Because of this design flexibility, the designer may choose a great number of MOSFETs for use in a wide variety of applications. The designer simply needs to know the MOSFET total gate charge (Q_G), and with this information a capacitor can be chosen. The capacitance of the storage capacitor should be greater than, or equal to, $Q_G/0.5V$.

The CPC1590 has two states of operation:
(1) sufficient input control current is flowing, the LED is turned on, and the gate current is being applied. The light from the LED is being reflected onto the photovoltaic, which then produces a photocurrent that

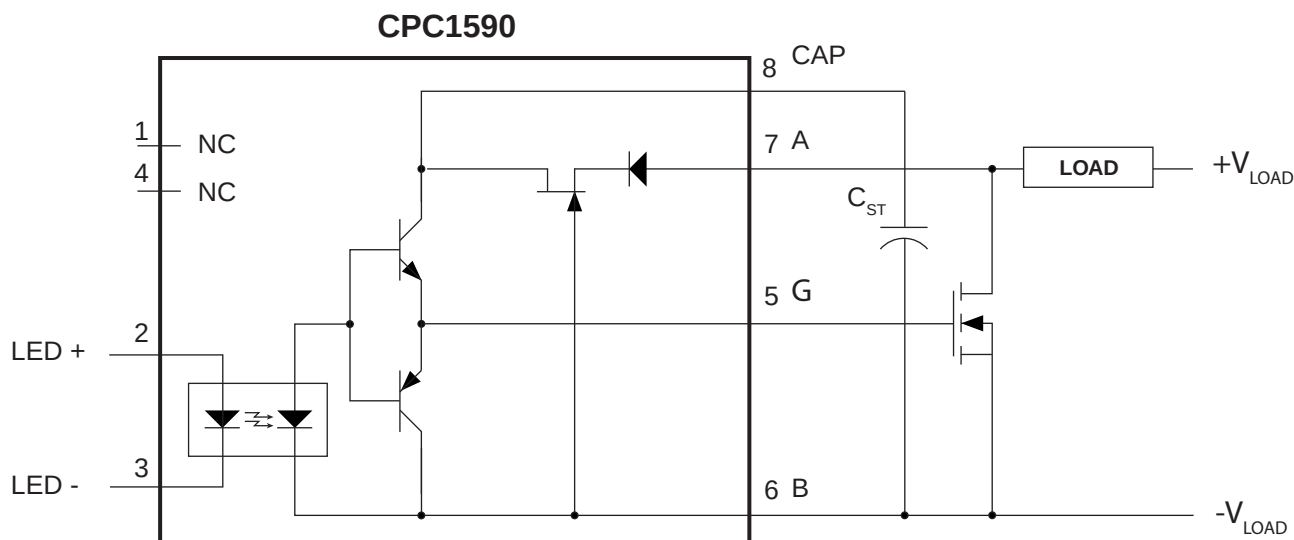
turns on the NPN bipolar transistor and provides the charge ($I \times t = Q$), or the gate current that is being applied to turn on the MOSFET. (2) Sufficient input control current is not flowing, the LED is turned off, and gate current is not flowing. The LED is off because $V_F \ll$ the minimum forward voltage required, and not enough current is being applied. This turns on the PNP bipolar transistor, providing a path for gate current to discharge to V_{L2} .

When V_{LOAD} is first applied, the external storage capacitor begins to charge. The charge is sent through a bootstrap diode to prevent the charge from escaping and discharging through a turned-on MOSFET. The J-FET then regulates the voltage between 10V and 16V. The input control current is applied, then the charge is transferred from the storage capacitor through the NPN bipolar transistor, along with the charge from the photovoltaic, to the MOSFET gate to accomplish a rapid turn-on. After the capacitor has discharged and the MOSFET has turned on, the photocurrent from the input optocoupler continues to flow into the gate to keep the MOSFET turned on.

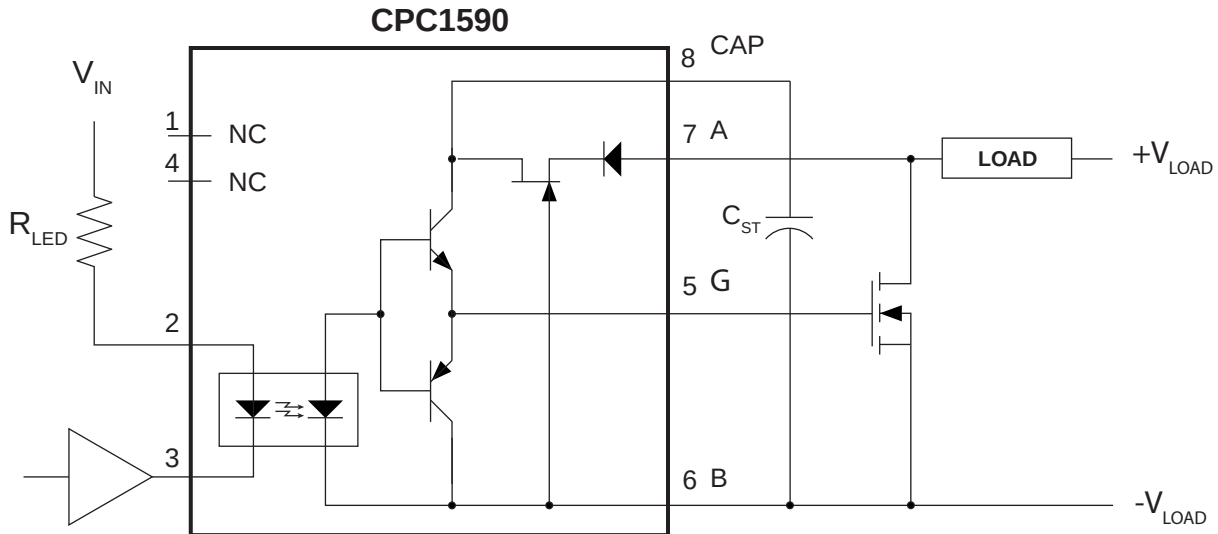
When the input control current is removed, the gate current stops flowing and the PNP bipolar transistor is on and is discharging the MOSFET gate. The MOSFET is now off. At this point the capacitor begins to recharge for the next turn on cycle.

The circuit below does not include over-voltage protection.

Figure 2. CPC1590 DC Application Circuit



4. Device Configuration



4.1 LED resistor

The input resistor is required to limit LED current to a value set by Recommended Operating Conditions in “**Recommended Operating Conditions**” on page 3. In some cases, higher LED operating current would improve driver speed; however, this higher current could also reduce LED lifespan, which would cause reliability issues.

The general equation used to calculate the resistor value is:

$$R_{LED} = \frac{V_{IN} - (V_F + V_{OL})}{I_F}$$

- I_F = Input Control Current
- V_{OL} = Low-level output of the driving logic gate or the collector-emitter voltage of the driving logic transistor. (This parameter is provided in the manufacturer's data sheet.)
- V_{IN} = Input Power Source
- V_F = Forward Voltage Drop of LED
- R_{LED} = Input Resistor

When calculating the resistor value, the designer should take into consideration power-supply variations, which can range about $\pm 10\%$, temperature variations from -40°C to $+85^\circ\text{C}$, LED forward voltage drop over the temperature range, and the resistor's tolerance and temperature stability rating.

When the LED resistor value is selected by the above formula, the R_{LED} power dissipation, P_D , can be obtained from the following equation:

$$P_D = I_F^2 \cdot R_{LED}$$

With power dissipation calculated, it is now possible to select an appropriate resistor size that can be used in the particular application circuit. It is recommended that a resistor with at least twice the calculated power rating should be selected.

4.2 Storage Capacitor

The storage capacitor (C_{ST}) enables the gate driver to turn on a power MOSFET faster by delivering a reservoir of charge to the gate. Selection of the storage capacitor is given by the following equation:

$$C_{ST} \geq Q_G / 0.5V$$

This equation shows that the storage capacitor needs to deliver enough charge to the gate while only dropping 0.5V. The CPC1590 can deliver 32nC of charge at rated operating speed, and will operate with much larger loads, $>4\text{nF}$, with slower turn-on and turn-off times.

The CPC1590 has an internal J-FET, which is used to regulate the voltage applied to the storage capacitor. The voltage applied to the storage capacitor will be

between 10V and 16V. The capacitor's voltage rating should be two to three times this range.

The designer should select the storage capacitor based on the particular application requirements. If the final product requires operating at a higher ambient temperature range of -40°C to $+110^{\circ}\text{C}$, then it is better to select COG/NPO capacitors in order to meet minimum capacitance requirements.

4.3 Transistor Selection

The CPC1590 charges and discharges an external MOSFET transistor. The selection of the MOSFET is determined by the user to meet the specific power

requirements for the load. The CPC1590 output voltage is listed in the specification, but, as mentioned earlier, there must be little or no gate leakage.

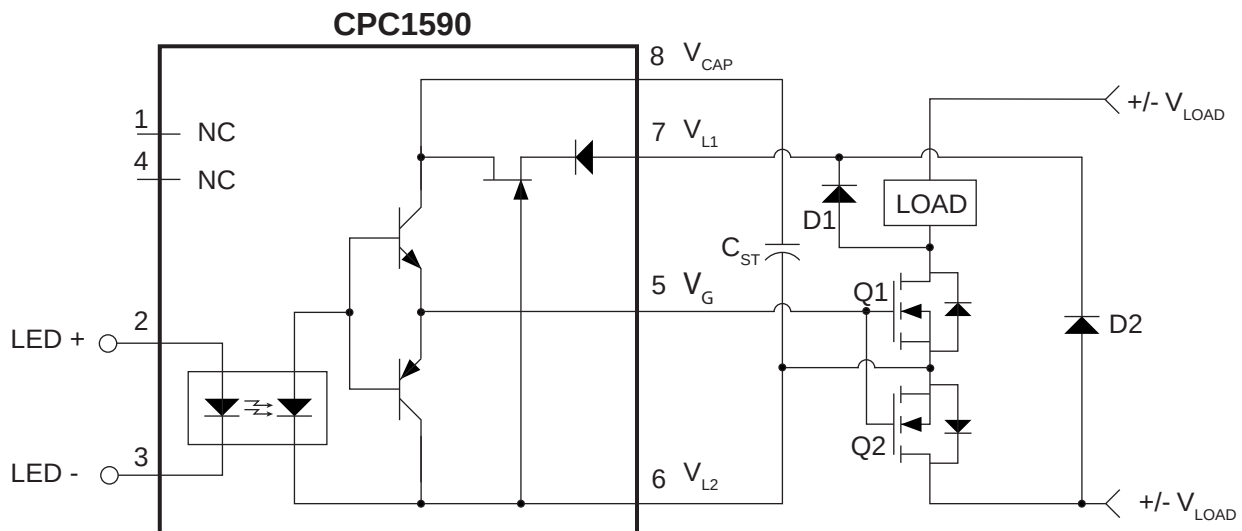
Another parameter that plays a significant role in the selection of the transistor is the gate drive voltage available from the part. The CPC1590 uses photovoltaic cells to collect the optical energy generated by the internal LED; to generate more voltage, the photovoltaic diodes are stacked. As such, the voltage of the photovoltaic stack reduces with increased temperature. The user must select a transistor that will maintain the load current at the maximum temperature, given the V_{GS} in the CPC1590 specifications.

5. CPC1590 Used as an AC Switch

The CPC1590 can be used in other configurations. One typical configuration is shown in **Figure 3**, which is called an AC Switch. This simply means that either terminal can be positive or negative. This configuration requires a second MOSFET (Q2) and two rectifying diodes (D1 and D2).

The design considerations are identical for this application. Diodes D1 and D2 must have voltage ratings greater than the breakdown voltage of the MOSFETs.

Figure 3. Application Circuit for Using the CPC1590 as an AC Switch



6. Conclusion

See IXYS Integrated Circuits' Application Note, AN-202, for a thorough discussion, and for examples of device usage, component selection, and over-voltage protection circuitry.

7. Manufacturing Information

7.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
CPC1590P	MSL 1

7.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

7.3 Reflow Profile

Provided in the table below is the Classification Temperature (T_C) of this product and the maximum dwell time the body temperature of this device may be ($T_C - 5$)°C or greater. The classification temperature sets the Maximum Body Temperature allowed for this device during lead-free reflow processes. For through-hole devices, and any other processes, the guidelines of **J-STD-020** must be observed.

Device	Classification Temperature (T_C)	Dwell Time (t_p)	Max Reflow Cycles
CPC1590P	260°C	30 seconds	3

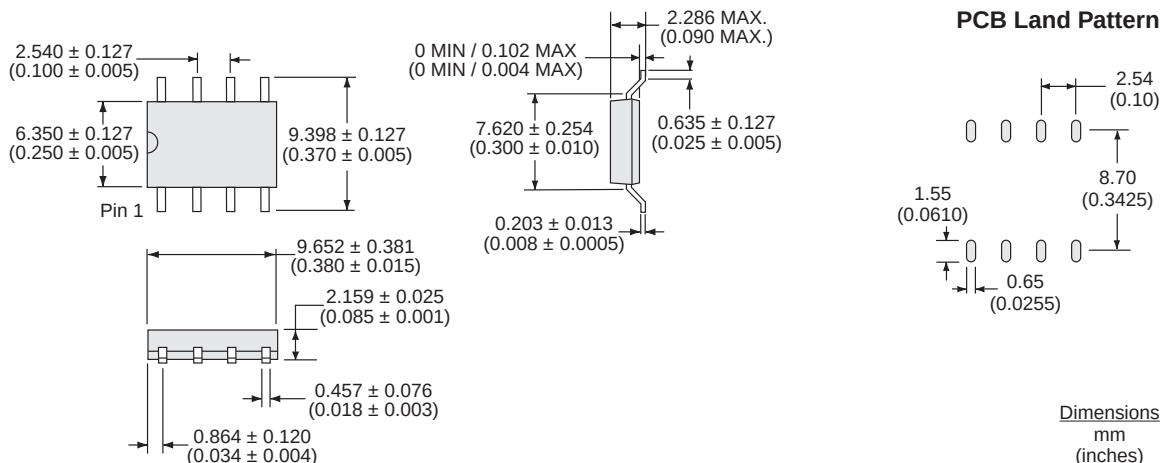
7.4 Board Wash

IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to flux or solvents that are Chlorine- or Fluorine-based.

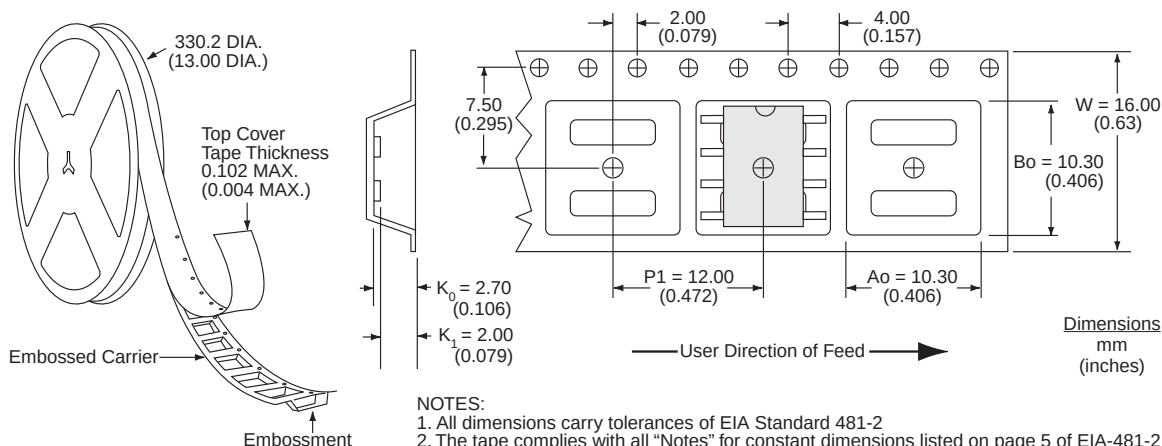


7.5 Mechanical Dimensions

7.5.1 CPC1590P 8-Pin Flatpack Package



7.5.2 CPC1590PTR Tape & Reel



For additional information please visit www.ixysic.com

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